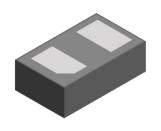


PTVSHC2EN24VUT

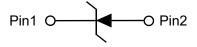
Uni-directional 24V High Capacitance TVS

Description

The PTVSHC2EN24VUT Transient Voltage Suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC2EN24VUT protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PTVSHC2EN24VUT is available in a DFN1610-2L package with working voltages of 24 volt.



DFN1610-2L(Bottom View)

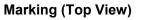


Circuit Diagram

Feature

- 2300W peak pulse power per line (t_P = 8/20µs)
- DFN1610-2L package
- Protect one I/O or power line
- Low clamping voltage
- ➢ RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ± 30kV(contact); IEC 61000-4-5 (Lightning) 75A (8/20us)





Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP4 players

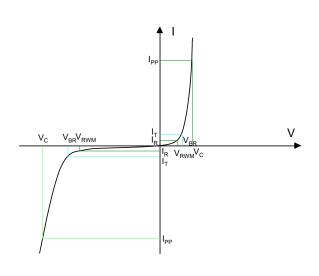
Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- > Pure tin plating: $7 \sim 17$ um
- ➢ Pin flatness:≤3mil

PTVSHC2EN24VUT

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{TRIG}	Reverse trigger Current		
V _{HOLD}	Reverse holding voltage		
Ι _Τ	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
V _c	Clamping Voltage @ I _{PP}		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
I _F	Forward Current		
V _F	Forward Voltage @ I _F		



Electrical characteristics per line@25°C (unless otherwise specified)

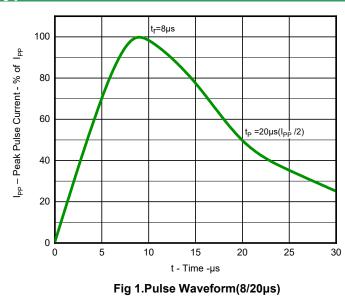
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}	-	-	-	24	V
Breakdown Voltage	V _{BR}	I _t = 1mA	26	-	30	V
Reverse Leakage Current	I _R	V _{RWM} = 24V	-	-	1	μA
Clamping Voltage	V _c	I _{PP} = 75A,t _P = 8/20μs	-	32	35	V
Junction Capacitance	CJ	V _R = 0V,f = 1MHz	-	230	300	pF

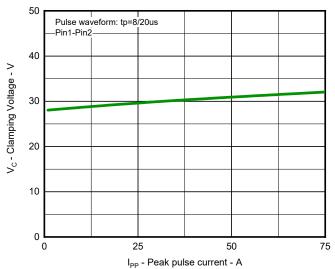
Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	2300	W
Peak Pulse Current (t _P = 8/20µs)	I _{PP}	75	А
Lead Soldering Temperature	TL	260 (10 sec)	°C
Junction and Storage Temperature Range	T _{J,} T _{STG}	-55~150	°C

PTVSHC2EN24VUT

Typical Characteristics







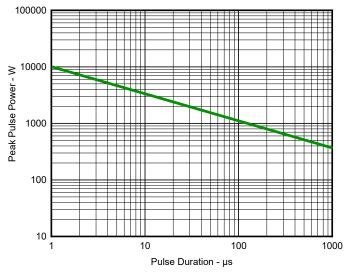
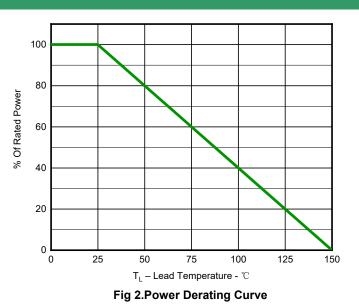
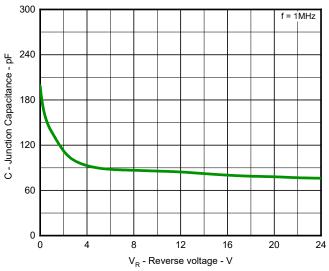
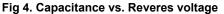


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time







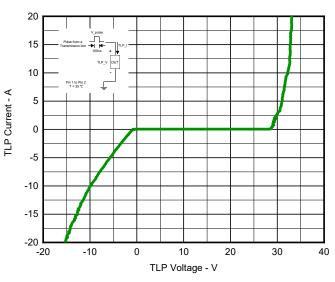
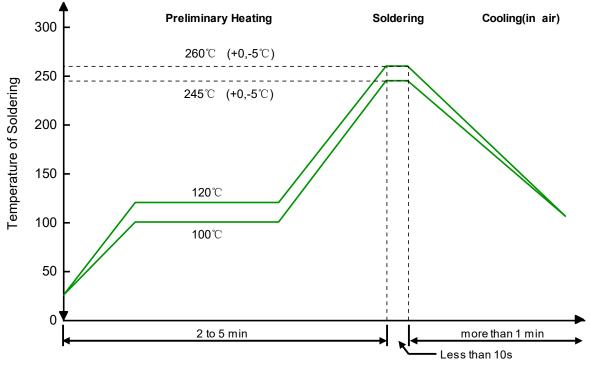


Fig 6. TLP Measurement

PTVSHC2EN24VUT

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PCB Design

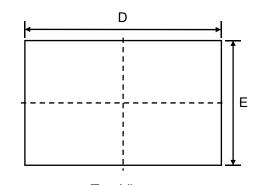
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

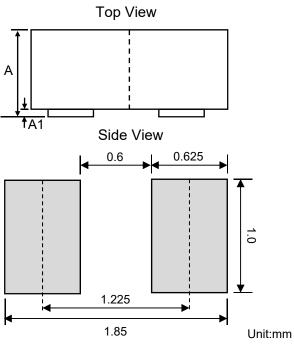
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

Device	Package	Reel	Shipping
PTVSHC2EN24VUT	DFN1610-2L (Pb-Free)	7"	3000 / Tape & Reel

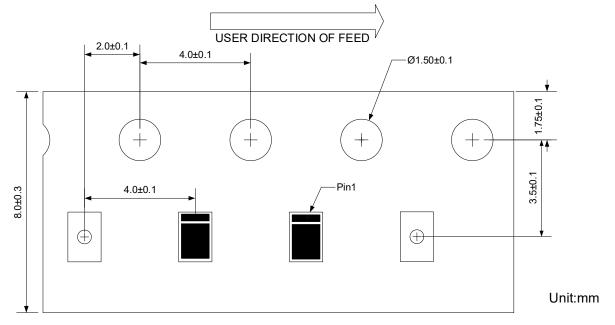
Product dimension (DFN1610-2L)





Suggested PCB Layout

Load with information



Dim	Millimeters		Inches		
	Min	Мах	Min	Max	
A	0.45	0.55	0.018	0.022	
A1	0.00	0.05	0.000	0.002	
b	0.75	0.85	0.030	0.033	
D	1.55	1.65	0.061	0.065	
E	0.95	1.05	0.037	0.041	
е	1.10 BSC		0.043 BSC		
L	0.35	0.45	0.014	0.018	
h	0.15	0.25	0.006	0.010	

PTVSHC2EN24VUT

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